

# THREE PHASE DIODE+THYRISTOR

## DFA150AA80/160

UL;E76102 (M)

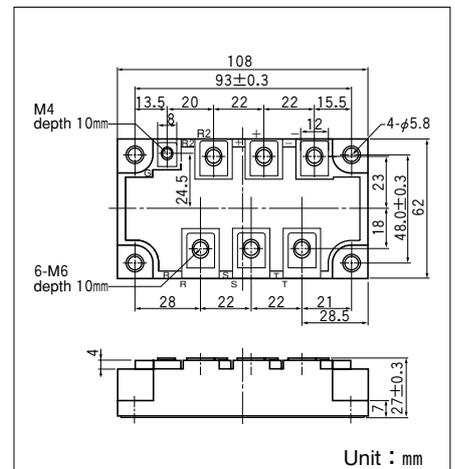
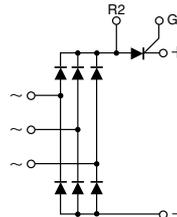
**SanRex** Power Module, DFA150AA, is complex isolated module which is designed for rash current circuit.

It contains six diodes connected in a three phase bridge configuration, and a thyristor connected to a direct current line.

- This Module is designed very compactly. Because diode module and thyristor put together.
- This Module is also isolated type between electorode terminal and mounting base. So you can put this Module and other one together in a same fin.

### (Application)

- Inverter for AC or DC motor control, Current stabilized power supply, Switching power supply.



Unit : mm

### ● DIODE

#### ■ Maximum Ratings

(T<sub>j</sub>=25°C unless otherwise specified)

Symbol	Item	Ratings		Unit
		DFA150AA80	DFA150AA160	
V <sub>RRM</sub>	Repetitive Peak Reverse Voltage	800	1600	V
V <sub>RSM</sub>	Non-Repetitive Peak Reverse Voltage	960	1700	V

Symbol	Item	Conditions	Ratings	Unit
I <sub>D</sub>	Output Current (D.C.)	Three phase full wave, T <sub>c</sub> =93°C	150	A
I <sub>FSM</sub>	Surge forward current	1 cycle, 50/60Hz, peak value, non-repetitive	1460/1600	A
T <sub>j</sub>	Operating Junction Temperature		-40 to +150	°C
T <sub>stg</sub>	Storage Temperature		-40 to +125	°C
V <sub>ISO</sub>	Isolation Breakdown Voltage (R.M.S.)	A.C. 1minute	2500	V
	Mounting Torque	Mounting (M5)	Recommended Value 1.5-2.5 (15-25)	2.7 (28)
		Terminal (M6)	Recommended Value 2.5-3.9 (25-40)	4.7 (48)
		Terminal (M4)	Recommended Value 1.0-1.4 (10-14)	1.5 (15)
	Mass	Typical Value	460	g

#### ■ Electrical Characteristics

Symbol	Item	Conditions	Ratings	Unit
I <sub>RRM</sub>	Repetitive Peak Reverse Current,max.	T <sub>j</sub> =150°C, V <sub>R</sub> =V <sub>RRM</sub>	15	mA
V <sub>FM</sub>	Forward Voltage Drop,max.	I <sub>F</sub> =150A, Inst. measurement	1.35	V
R <sub>th(j-c)</sub>	Thermal Impedance, max.	Junction to Case (TOTAL)	0.14	°C/W
R <sub>th(c-f)</sub>	Thermal Impedance, max.	Case to fin	0.07	°C/W

# DFA150AA80/160

## ● THYRISTOR

### ■ Maximum Ratings

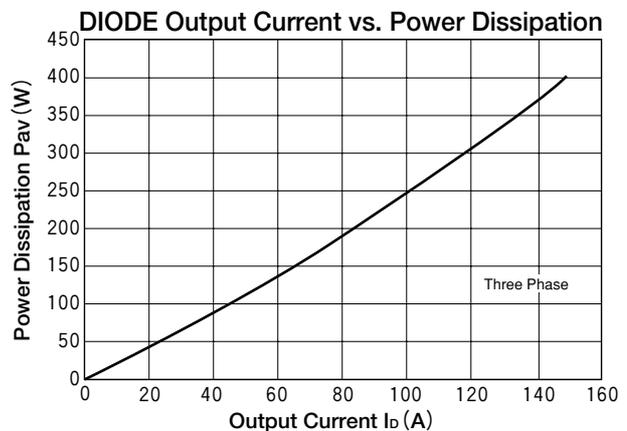
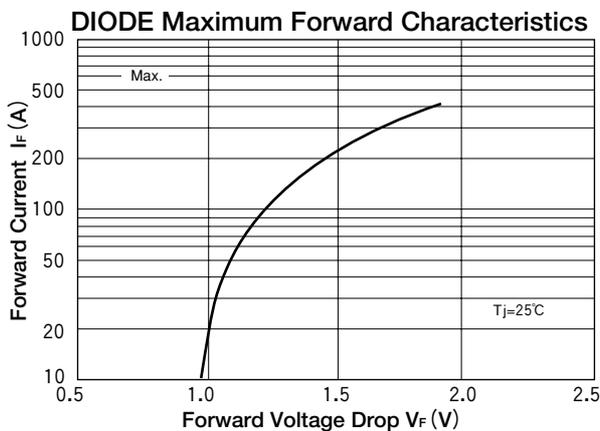
(T<sub>j</sub>=25°C unless otherwise specified)

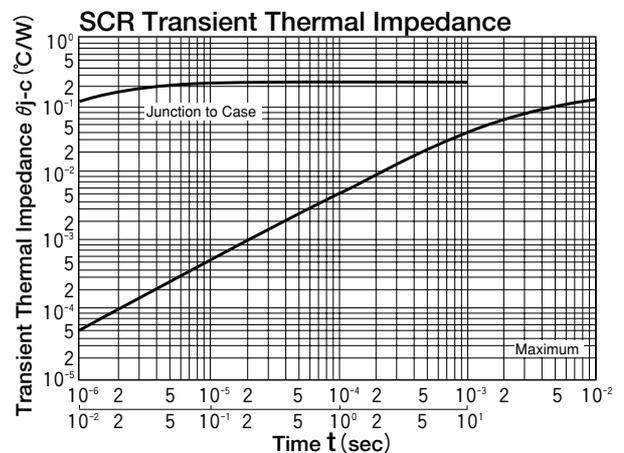
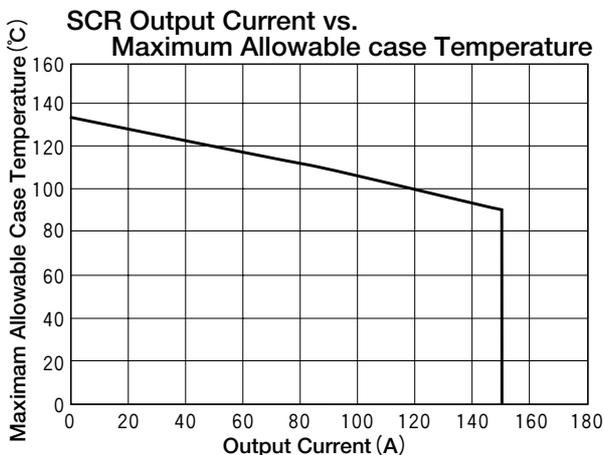
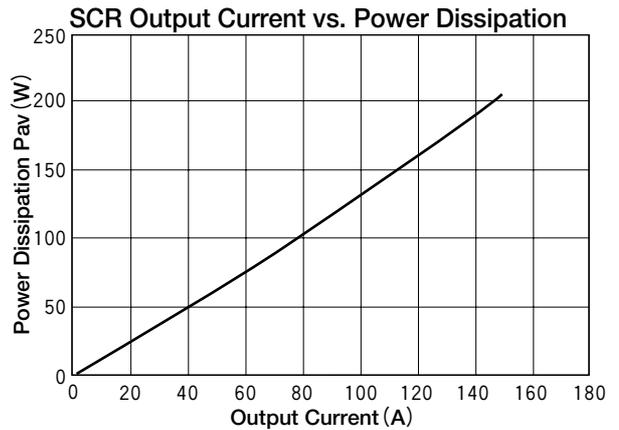
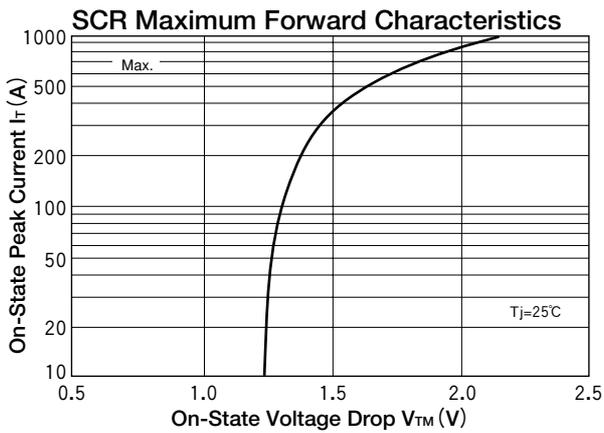
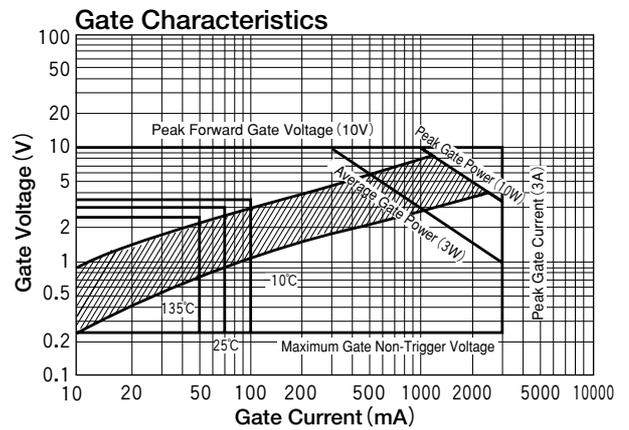
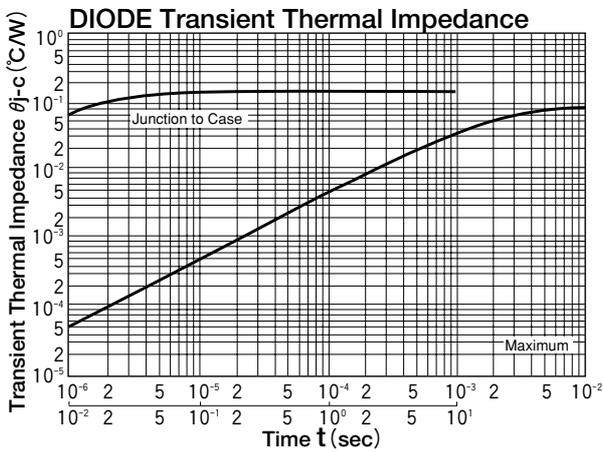
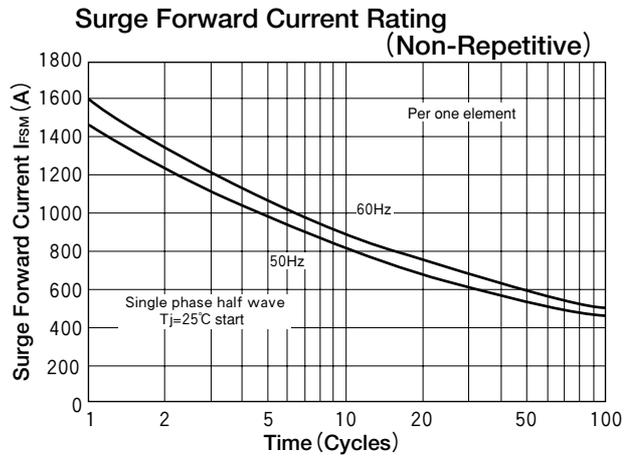
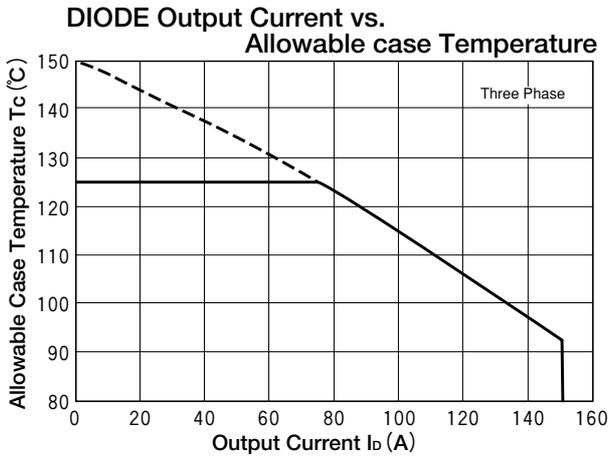
Symbol	Item	Ratings		Unit
		DFA150AA80	DFA150AA160	
V <sub>RRM</sub>	Repetitive Peak Reverse Voltage	800	1600	V
V <sub>RSM</sub>	Non-Repetitive Peak Reverse Voltage	960	1700	V
V <sub>DRM</sub>	Repetitive Peak off-State Voltage	800	1600	V

Symbol	Item	Conditions	Ratings	Unit	
I <sub>T(AV)</sub>	Average On-State Current	Singl phase half wave. 180° conduction, T <sub>c</sub> =93°C	150	A	
I <sub>TSM</sub>	Surge On-State Current	1 cycle, 50/60Hz, peak value, non-repetitive	1460/1600	A	
I <sup>2</sup> t	I <sup>2</sup> t (for fusing)		10670	A <sup>2</sup> S	
di/dt	Critical Rate of Rise of On-State Current	I <sub>G</sub> =100mA, V <sub>D</sub> =½V <sub>DRM</sub> , di <sub>G</sub> /dt=0.1A/μs	150	A/μs	
V <sub>ISO</sub>	Isolation Breakdown Voltage (R.M.S.)	A.C. 1minute	2500	V	
T <sub>j</sub>	Operating Junction Temperature		-40 to +135	°C	
T <sub>stg</sub>	Storage Temperature		-40 to +125	°C	
	Mounting Torque	Mounting (M5)	Recommended Value 1.5-2.5 (15-25)	2.7 (28)	N·m (kgf·cm)
		Terminal (M6)	Recommended Value 2.5-3.9 (25-40)	4.7 (48)	
		Terminal (M4)	Recommended Value 1.0-1.4 (10-14)	1.5 (15)	
	Mass	Typical Value	460	g	

### ■ Electrical Characteristics

Symbol	Item	Conditions	Ratings	Unit
I <sub>DRM</sub>	Repetitive Peak Off-State Current,max.	T <sub>j</sub> =135°C, V <sub>D</sub> =V <sub>DRM</sub>	100	mA
I <sub>RRM</sub>	Repetitive Peak Reverse Current,max.	T <sub>j</sub> =135°C, V <sub>D</sub> =V <sub>RRM</sub>	100	mA
V <sub>TM</sub>	Peak On-State Voltage,max.	T <sub>j</sub> =25°C, I <sub>TM</sub> =150A, , Inst. measurement	1.35	V
I <sub>GT</sub>	Gate Trigger Current,max.	T <sub>j</sub> =25°C, V <sub>D</sub> =6V, I <sub>T</sub> =1A	70	mA
V <sub>GT</sub>	Gate Trigger Voltage,max.	T <sub>j</sub> =25°C, V <sub>D</sub> =6V, I <sub>T</sub> =1A	3	V
dv/dt	Critical Rate of Rise of Off-State Voltage,min.	T <sub>j</sub> =125°C, V <sub>D</sub> =⅔V <sub>DRM</sub>	500	V/μs
R <sub>th(j-c)</sub>	Thermal Impedance, max.	Junction to Case	0.21	°C/W
R <sub>th(c-f)</sub>	Thermal Impedance, max.	Case to fin	0.07	°C/W





## X-ON Electronics

Largest Supplier of Electrical and Electronic Components

*Click to view similar products for [Discrete Semiconductor Modules](#) category:*

*Click to view products by [Sanrex](#) manufacturer:*

Other Similar products are found below :

[M252511FV](#) [DD260N12K-A](#) [DD380N16A](#) [DD89N1600K-A](#) [APT2X21DC60J](#) [APT58M80J](#) [B522F-2-YEC](#) [MSTC90-16](#) [25.163.0653.1](#)  
[25.163.2453.0](#) [25.163.4253.0](#) [25.190.2053.0](#) [25.194.3453.0](#) [25.320.4853.1](#) [25.320.5253.1](#) [25.326.3253.1](#) [25.326.3553.1](#) [25.330.1653.1](#)  
[25.330.4753.1](#) [25.330.5253.1](#) [25.334.3253.1](#) [25.334.3353.1](#) [25.350.2053.0](#) [25.352.4753.1](#) [25.522.3253.0](#) [T483C](#) [T484C](#) [T485F](#) [T485H](#)  
[T512F-YEB](#) [T513F](#) [T514F](#) [T554](#) [T612FSE](#) [25.161.3453.0](#) [25.179.2253.0](#) [25.194.3253.0](#) [25.325.1253.1](#) [25.326.4253.1](#) [25.330.0953.1](#)  
[25.332.4353.1](#) [25.350.1653.0](#) [25.350.2453.0](#) [25.352.1453.0](#) [25.352.1653.0](#) [25.352.2453.0](#) [25.352.5453.1](#) [25.522.3353.0](#) [25.602.4053.0](#)  
[25.640.5053.0](#)